

10/549683

JC20 Rec'd PCT/PTO 19 SEP 2005

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re U.S. Patent Application of )  
SUDA et al. )  
Application Number: To Be Assigned )  
Filed: Concurrently Herewith )  
For: METHOD OF GROWING SEMICONDUCTOR )  
CRYSTAL )  
ATTORNEY DOCKET No. HIRA.0204 )

**Honorable Assistant Commissioner  
for Patents  
Washington, D.C. 20231**

**INFORMATION DISCLOSURE STATEMENT**

Pursuant to 37 C.F.R. §§ 1.56 and 1.97, this Information Disclosure Statement is submitted in the above-identified National Stage U.S. patent application. A listing of documents to be published on the face of any patent granted from this application is submitted herewith on Form PTO-1449. Any other documents or information submitted for consideration by the Examiner are listed in this paper. A copy of each foreign patent, or each publication or portion thereof listed or herein identified, is submitted herewith.

**CERTIFICATION**

This Information Disclosure Statement is submitted with the initial filing of the application. Accordingly, no fee is due or payable at this time.

The Examiner is requested to acknowledge consideration of the information provided in this paper in accordance with prescribed procedures.

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Please charge any additional fees or credit any overpayments in connection with this paper to Deposit Account No. 08-1480.

Respectfully submitted,

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Stanley P. Fisher  
Registration Number 24,344

Juan Carlos A. Marquez  
Registration No. 34,072

**REED SMITH LLP**  
3110 Fairview Park Drive  
Suite 1400  
Falls Church, Virginia 22042  
(703) 641-4200

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Form PTO 1449  U.S. Department of Commerce Patent and Trademark Office  Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER HIRA.0204	SERIAL NUMBER To be Assigned <b>107549683</b>
	APPLICANT SUDA et al.	
	FILING DATE Concurrently Herewith	GROUP

## U.S. Patent Documents

Examiner Initial		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE

## Foreign Patent Documents

**Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)**

		International Search Report for Application Serial No. PCT/JP2004/003689 dated July 6, 2004
		Norio Onojima et al., "Molecular-Beam Epitaxial Growth of Insulating AlN on Surface-Controlled 6H-SiC Substrate by HCl Gas Etching", Applied Physics Letters, Volume 80, Number 1 (7 January 2002), pp. 76-78.
EXAMINER		DATE CONSIDERED

*EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant*

PTO1449